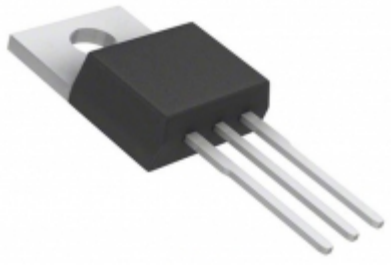








	<h2 style="color: red;">FQP17N08</h2>
	<p>Hersteller-Teilenummer: FQP17N08</p> <p>Hersteller / Marke: Fairchild/ON Semiconductor</p> <p>Teil der Beschreibung: MOSFET N-CH 80V 16.5A TO-220</p> <p>Datenblätter: 1.FQP17N08.pdf 2.FQP17N08.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 939 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	FQP17N08
Hersteller	Fairchild/ON Semiconductor
Beschreibung	MOSFET N-CH 80V 16.5A TO-220
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	939 pcs Stock
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-220-3
Supplier Device-Gehäuse	TO-220-3
Verlustleistung (max)	65W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	80V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	16.5A (Tc)
Rds On (Max) @ Id, Vgs	115 mOhm @ 8.25A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	15nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	450pF @ 25V
Verpackung	Tube

FQP17N08 ist neu im Original, Suche FQP17N08 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQP17N08 Fairchild/ON Semiconductor mit Garantie und Vertrauen.
Anfrage FQP17N08: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FQP16N35 FA FQP16N35 FA</p>	 <p>FQP16N25 AMI Semiconductor / ON Semiconductor MOSFET N-CH 250V 16A TO-220</p>	 <p>FQP17N08L AMI Semiconductor / ON Semiconductor MOSFET N-CH 80V 16.5A TO-220</p>	 <p>FQP16N25 Fairchild/ON Semiconductor MOSFET N-CH 250V 16A TO-220</p>
 <p>FQP17N40 AMI Semiconductor / ON Semiconductor MOSFET N-CH 400V 16A TO-220</p>	 <p>FQP16N25C Fairchild/ON Semiconductor MOSFET N-CH 250V 15.6A TO-220</p>	 <p>FQP17N08L Fairchild/ON Semiconductor MOSFET N-CH 80V 16.5A TO-220</p>	 <p>FQP16N25C AMI Semiconductor / ON Semiconductor MOSFET N-CH 250V 15.6A TO-220</p>

heiße Teile

Mehr

⊗ FQP13N50C	↔ FQP13N60C	⇒ FQP140N03	D FQP140N03L	↔ FQP14N15
⊣ FQP14N15	⊗ FQP14N30	D FQP14N30	⇒ FQP14N80	↔ FQP14N80C
⊗ FQP15N16	⊣ FQP15N30	⊗ FQP15N50	↔ FQP15N60	↔ FQP15N65
D FQP15N80	⊗ FQP15P12	⊣ FQP15P12	⊗ FQP16N15	↔ FQP16N15
⇒ FQP16N25	↔ FQP16N25	⊗ FQP16N25C	⊣ FQP16N25C	↔ FQP17N08
↔ FQP17N08L	⇒ FQP17N08L	D FQP17N40	⊗ FQP17N40	⊣ FQP17P06
⊗ FQP17P06	D FQP17P10	⇒ FQP17P10	↔ FQP18N20V2	↔ FQP18N20V2
⊣ FQP18N50V2	⊗ FQP18N50V2	↔ FQP19N10	⇒ FQP19N10	↔ FQP19N10L
⊗ FQP19N10L	⊣ FQP19N20	⊗ FQP19N20	D FQP19N20C	↔ FQP19N20C
↔ FQP19N20L	⊗ FQP19N20L	⊣ FQP1N60C	⊗ FQP20N06	↔ FQP20N06

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